

Product data sheet

1. General description

Dual common cathode power Schottky diode designed for high frequency switched mode power supplies in a TO-262 plastic package.

2. Features and benefits

- Trench structure
- High junction temperature up to 150°C
- High efficiency
- Low forward voltage drop, negligible switching losses

3. Applications

- DC to DC converters
- Freewheeling diode
- OR-ing diode

4. Quick reference data

Table 1. Quio	ck reference data						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{RRM}	repetitive peak reverse voltage			-	-	100	V
I _{F(AV)}	average forward current	$\delta = 0.5$; T _{mb} \leq 134 °C; square-wave pulse; per diode; <u>Fig. 1</u> ; <u>Fig. 2</u> ; <u>Fig. 3</u>		-	-	20	A
I _{O(AV)}	average output current	δ = 0.5 ; T _{mb} ≤ 130 °C; square-wave pulse; both diodes conducting		-	-	40	A
Static chara	acteristics	·	· · ·				
V _F	forward voltage	I _F = 10 A; T _j = 25 °C; <u>Fig. 6</u> ; per diode		-	0.53	0.59	V
		I _F = 10 A; T _j = 125 °C; <u>Fig. 6</u> ; per diode		-	0.49	0.56	V
		I _F = 20 A; T _j = 25 °C; <u>Fig. 6</u> ; per diode		-	0.64	0.71	V
		I _F = 20 A; T _j = 125 °C; <u>Fig. 6</u> ; per diode		-	0.61	0.68	V
I _R	reverse current	V _R = 100 V; T _j = 25 °C; <u>Fig. 7; Fig. 8;</u> per diode		-	-	50	μA
		V _R = 100 V; T _j = 125 °C; <u>Fig. 7</u> ; <u>Fig. 8</u> ; per diode		-	-	40	mA

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5. Pinning information

Table 2. Pinning information								
Pin	Symbol	Description	Simplified outline	Graphic symbol				
1	A1	anode 1						
2	К	cathode	0					
3	A2	anode 2	1 2 3 TO-262E	K sym125				
mb	К	mounting base; connected to cathode						

6. Ordering information

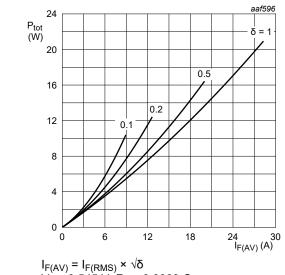
Table 3. Ordering information Type number Package Name Description Version WNS40H100CG TO-262 plastic single-ended package (I2PAK); 3 leads TO-262 TO-262E

7. Limiting values

Table 4. Limiting values

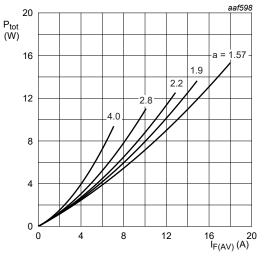
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{RRM}	repetitive peak reverse voltage		-	100	V
V _{RWM}	limiting crest working reverse voltage		-	100	V
V _R	limiting reverse voltage	DC	-	100	V
I _{F(AV)}	average forward current	δ = 0.5 ; T _{mb} ≤ 134 °C; square-wave pulse; per diode; <u>Fig. 1</u> ; <u>Fig. 2</u> ; <u>Fig. 3</u>	-	20	A
I _{O(AV)}	average output current	δ = 0.5 ; T _{mb} ≤ 130 °C; square-wave pulse; both diodes conducting	-	40	A
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; per diode; <u>Fig. 4</u>	-	380	A
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; per diode	-	418	A
T _{stg}	storage temperature		-40	150	°C
Tj	junction temperature		-	150	°C



 $V_{o} = 0.545 \text{ V}; \text{ R}_{s} = 0.0069 \Omega$

Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values; per diode



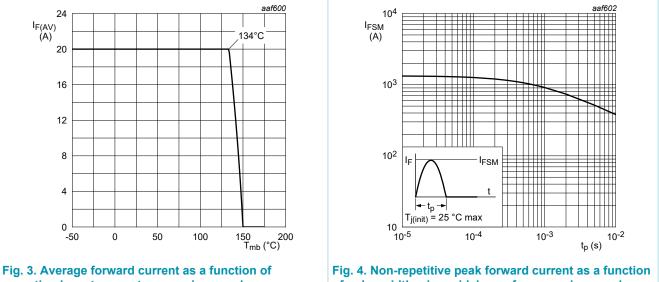
a = form factor = I $_{F(RMS)}$ / I $_{F(AV)}$ V $_o$ = 0.545 V; R $_s$ = 0.0069 Ω

Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values; per diode

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mounting base temperature; maximum values; per diode

Fig. 4. Non-repetitive peak forward current as a function of pulse width; sinusoidal waveform; maximum values; per diode

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8. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	per diode; <u>Fig. 5</u>	-	-	1	K/W
		both diodes conducting	-	-	0.6	K/W
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	-	60	-	K/W

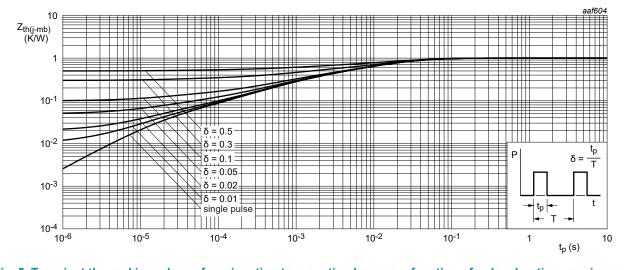
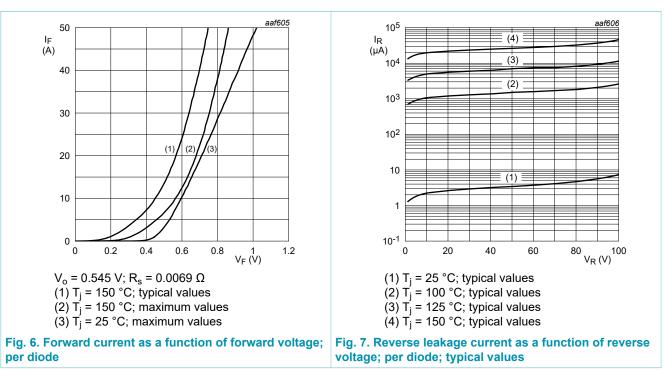


Fig. 5. Transient thermal impedance from junction to mounting base as a function of pulse duration; maximum values; per diode

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9. Characteristics

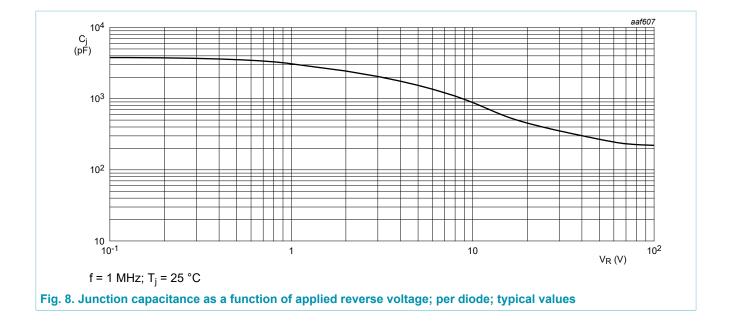
Table 6. Cha	racteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
V _F	forward voltage	I _F = 10 A; T _j = 25 °C; <u>Fig. 6;</u> per diode	-	0.53	0.59	V
		I _F = 10 A; T _j = 125 °C; <u>Fig. 6;</u> per diode	-	0.49	0.56	V
		I _F = 20 A; T _j = 25 °C; <u>Fig. 6;</u> per diode	-	0.64	0.71	V
		I _F = 20 A; T _j = 125 °C; <u>Fig. 6</u> ; per diode	-	0.61	0.68	V
I _R	reverse current	V _R = 100 V; T _j = 25 °C; <u>Fig. 7; Fig. 8;</u> per diode	-	-	50	μA
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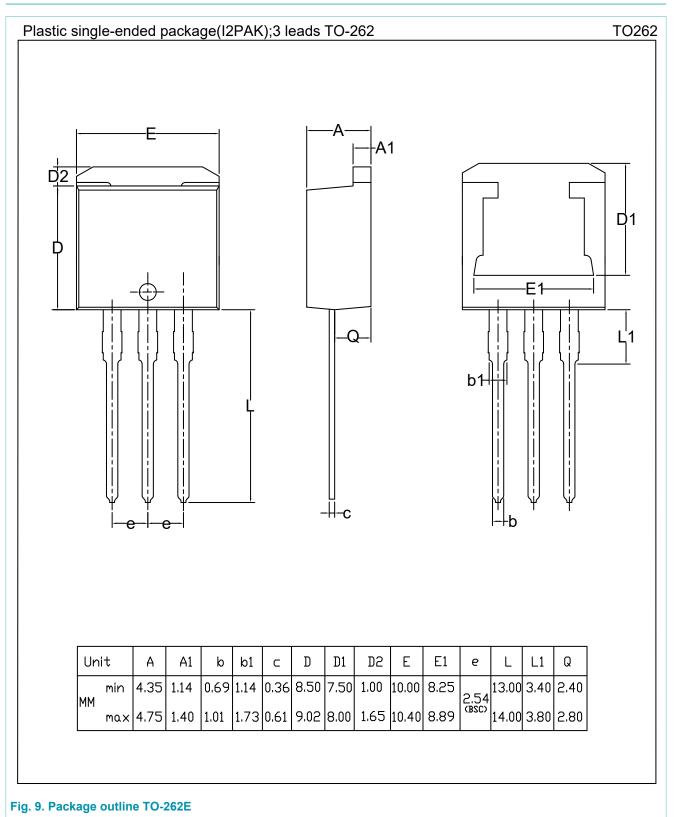
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10. Package outline



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11. Legal information

Data sheet status

Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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